ESP32-C3-WROOM-02 ESP32-C3-WROOM-02U

Datasheet Version 1.6

2.4 GHz Wi-Fi (802.11b/g/n) and Bluetooth® 5 module Built around ESP32-C3 series of SoCs, RISC-V single-core microprocessor Flash up to 16 MB 15 GPIOs

On-board PCB antenna or external antenna connector



ESP32-C3-WROOM-02



ESP32-C3-WROOM-02U



1 Module Overview

Note:

Check the link or the QR code to make sure that you use the latest version of this document: https://www.espressif.com/documentation/esp32-c3-wroom-02_datasheet_en.pdf



1.1 Features

CPU and On-Chip Memory

- ESP32-C3 embedded, 32-bit RISC-V single-core processor, up to 160 MHz
- 384 KB ROM
- 400 KB SRAM (16 KB for cache)
- 8 KB SRAM in RTC

Wi-Fi

- IEEE 802.11b/g/n-compliant
- Center frequency range of operating channel:
 2412 ~ 2484 MHz
- Supports 20 MHz, 40 MHz bandwidth in 2.4 GHz band
- 1T1R mode with data rate up to 150 Mbps
- Wi-Fi Multimedia (WMM)
- TX/RX A-MPDU. TX/RX A-MSDU
- Immediate Block ACK
- Fragmentation and defragmentation
- Transmit opportunity (TXOP)
- Automatic Beacon monitoring (hardware TSF)
- 4 × virtual Wi-Fi interfaces
- Simultaneous support for Infrastructure BSS in Station mode, SoftAP mode, Station + SoftAP mode, and promiscuous mode
 Note that when ESP32-C3 series scans in Station mode, the SoftAP channel will change along with the Station channel
- 802.11mc FTM

Bluetooth®

- Bluetooth LE: Bluetooth 5, Bluetooth mesh
- Speed: 125 Kbps, 500 Kbps, 1 Mbps, 2 Mbps
- Advertising extensions
- Multiple advertisement sets
- Channel selection algorithm #2
- Internal co-existence mechanism between Wi-Fi and Bluetooth to share the same antenna

Peripherals

- Up to 15 GPIOs
 - 3 strapping GPIOs
- SPI, UART, I2C, I2S, remote control peripheral, LED PWM controller, general DMA controller, TWAI® controller (compatible with ISO 11898-1, i.e. CAN Specification 2.0), USB Serial/JTAG controller, temperature sensor, SAR ADC, general-purpose timers, watchdog timers

Note:

* Please refer to <u>ESP32-C3 Series Datasheet</u> for detailed information about the module peripherals

Integrated Components on Module

- 40 MHz crystal oscillator
- SPI flash

Antenna Options

• ESP32-C3-WROOM-02: On-board PCB antenna

• ESP32-C3-WROOM-O2U: External antenna via a connector

Certification

• RF certification: See certificates

• Green certification: RoHS/REACH

Operating Conditions

• Operating voltage/Power supply: 3.0 ~ 3.6 V

• Operating ambient temperature:

- 85 °C version module: -40 ~ 85 °C

- 105 °C version module: -40 ~ 105 °C

55 6 Version module. 46 65 6

Test

HTOL/HTSL/uHAST/TCT/ESD/Latch-up

1.2 Series Comparison

ESP32-C3-WROOM-O2 and ESP32-C3-WROOM-O2U are two general-purpose Wi-Fi and Bluetooth LE modules. The rich set of peripherals and high performance make the two modules an ideal choice for smart homes, industrial automation, health care, consumer electronics, etc.

ESP32-C3-WROOM-O2 and ESP32-C3-WROOM-O2U both feature an external SPI flash.

ESP32-C3-WROOM-O2 comes with a on-board PCB antenna. ESP32-C3-WROOM-O2U comes with a connector for an external antenna.

A wide selection of module variants are available as shown in Table 1-1 and 1-2.

Table 1-1. ESP32-C3-WROOM-02 (ANT) Series Comparison¹

Ordering Code	Flash ^{4, 7}	Ambient Temp. ² (°C)	Embedded Chip Revision	Size ³ (mm)
ESP32-C3-WROOM-02-N4	4 MB (Quad SPI)	-40 ∼ 85	v0.4	18.0 × 20.0 × 3.2
ESP32-C3-WROOM-02-H4	4 MD (Quad SPI)	-40 ∼ 105	v0.4	10.0 ^ 20.0 ^ 3.2

¹ This table shares the same notes presented in Table 1-2 below.

Table 1-2. ESP32-C3-WROOM-02U (CONN) Series Comparison

Ordering Code	Flash ^{4, 7}	Ambient Temp. ² (°C)	Embedded Chip Revision	Size ³ (mm)
ESP32-C3-WROOM-02U-N4	4 MB (Quad SPI)	-40 ∼ 85	v0.4	18.0 × 14.3 × 3.2
ESP32-C3-WROOM-02U-H4	4 MD (Quad SFI)	-40 ∼ 105	v0.4	10.0 ^ 14.3 ^ 3.2

² Ambient temperature specifies the recommended temperature range of the environment immediately outside the Espressif module.

Both ESP32-C3-WROOM-O2 and ESP32-C3-WROOM-O2U has two operating ambient temperature options: $-40 \sim 85$ °C variants and $-40 \sim 105$ °C variants, all embedded with the ESP32-C3 chip.

Note:

For more information on ESP32-C3, please refer to <u>ESP32-C3 Series Datasheet</u>.

For chip revision identification, ESP-IDF release that supports a specific chip revision, and other information on chip revisions, please refer to ESP32-C3 Series SoC Errata > Section Chip Revision.

1.3 Applications

- Smart Home
- Industrial Automation
- Health Care
- Consumer Electronics
- Smart Agriculture

- POS Machines
- Service Robot
- Audio Devices
- Generic Low-power IoT Sensor Hubs
- Generic Low-power IoT Data Loggers

³ For details, refer to Section 10.1 *Module Dimensions*.

⁴ All modules can be equipped with 8 MB or 16 MB flash. For specifications, refer to Section 6.5 *Memory Specifications*.

 $^{^5}$ Customized version operating at –40 \sim 105 °C is available. For details, please contact our sales team.

⁶ All chip revisions have the same SRAM size, but chip revision v1.1 has around 10 KB more available space for users than chip revision v0.4. Chip revision v1.1 depends on specific ESP-IDF versions, as detailed in Compatibility Advisory for ESP32-C3 Chip Revision v1.1. For how to identify chip revisions, please refer to ESP32-C3 Series SoC Errata.

⁷ By default, the SPI flash on the module operates at a maximum clock frequency of 80 MHz and does not support the auto suspend feature. If you have a requirement for a higher flash clock frequency of 120 MHz or if you need the flash auto suspend feature, please contact us.

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2 Block Diagram

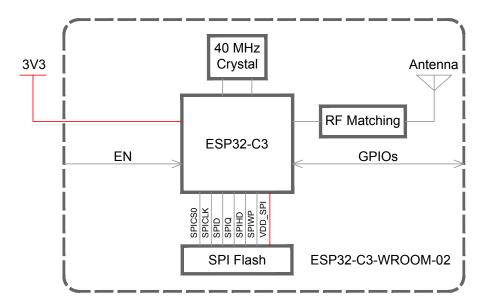


Figure 2-1. ESP32-C3-WROOM-02 Block Diagram

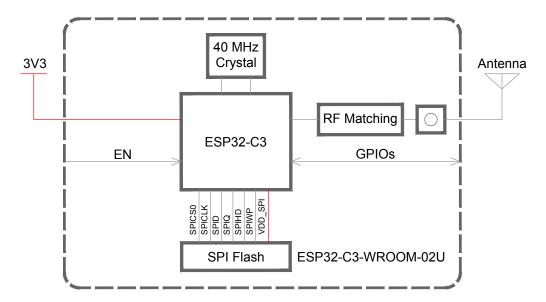
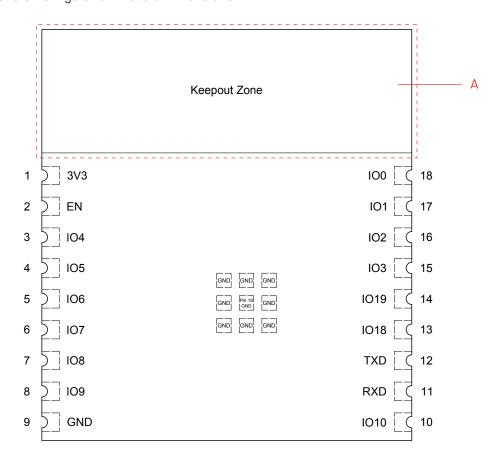


Figure 2-2. ESP32-C3-WROOM-02U Block Diagram

3 Pin Definitions

3.1 Pin Layout

The pin diagram below shows the approximate location of pins on the module. For the actual diagram drawn to scale, please refer to Figure 10.1 *Module Dimensions*.



Note A:

The zone marked with dotted lines is the antenna keepout zone. The pin diagram is applicable to ESP32-C3-WROOM-02 and ESP32-C3-WROOM-02U, but the latter has no antenna keepout zone.

To learn more about the keepout zone for module's antenna on the base board, please refer to ESP32-C3 Hardware Design Guidelines > Section General Principles of PCB Layout for Modules.

3.2 Pin Description

The module has 19 pins. See pin definitions in Table 3-1 Pin Definitions.

For peripheral pin configurations, please refer to Section 5.2 Peripheral Description.

Table 3-1. Pin Definitions

Name	No.	Type ¹	Function
3V3	1	Р	Power supply

Cont'd on next page

Table 3-1 – cont'd from previous page

Name	No.	Type ¹	Function
EN	2	ı	High: on, enables the chip.
LIN		l I	Low: off, the chip powers off.
			Note: Do not leave the EN pin floating.
104	3	I/O/T	GPIO4, ADC1_CH4, FSPIHD, MTMS
105	4	I/O/T	GPIO5, ADC2_CHO, FSPIWP, MTDI
106	5	I/O/T	GPIO6, FSPICLK, MTCK
107	6	I/O/T	GPIO7, FSPID, MTDO
108	7	I/O/T	GPIO8
109	8	I/O/T	GPIO9
GND	9,19	Р	Ground
1010	10	I/O/T	GPIO10, FSPICSO
RXD	11	I/O/T	GPIO20, UORXD
TXD	12	I/O/T	GPIO21, UOTXD
1018	13	I/O/T	GPIO18, USB_D-
1019	14	I/O/T	GPIO19, USB_D+
103	15	I/O/T	GPIO3, ADC1_CH3
102	16	I/O/T	GPIO2, ADC1_CH2, FSPIQ
IO1	17	I/O/T	GPIO1, ADC1_CH1, XTAL_32K_N
100	18	I/O/T	GPIOO, ADC1_CHO, XTAL_32K_P

¹ P: power supply; I: input; O: output; T: high impedance.

4 Boot Configurations

Note:

The content below is excerpted from <u>ESP32-C3 Series Datasheet</u> > Section Boot Configurations. For the strapping pin mapping between the chip and modules, please refer to Chapter 8 <u>Module Schematics</u>.

The chip allows for configuring the following boot parameters through strapping pins and eFuse parameters at power-up or a hardware reset, without microcontroller interaction.

Chip boot mode

- Strapping pins: GPIO2, GPIO8, and GPIO9

ROM message printing

- Strapping pin: GPIO8

- eFuse parameters: EFUSE_UART_PRINT_CONTROL and EFUSE_USB_PRINT_CHANNEL

The default values of all the above eFuse bits are 0, which means that they are not burnt. Given that eFuse is one-time programmable, once an eFuse bit is programmed to 1, it can never be reverted to 0. For how to program eFuse bits, please refer to ESP32-C3 Technical Reference Manual > Chapter eFuse Controller.

The default values of the strapping pins, namely the logic levels, are determined by pins' internal weak pull-up/pull-down resistors at reset if the pins are not connected to any circuit, or connected to an external high-impedance circuit.

Strapping Pin	Default Configuration	Bit Value
GPIO2	Floating	_
GPIO8	Floating	-
GPIO9	Weak pull-up	1

Table 4-1. Default Configuration of Strapping Pins

To change the bit values, the strapping pins should be connected to external pull-down/pull-up resistances. If the ESP32-C3 is used as a device by a host MCU, the strapping pin voltage levels can also be controlled by the host MCU.

All strapping pins have latches. At Chip Reset, the latches sample the bit values of their respective strapping pins and store them until the chip is powered down or shut down. The states of latches cannot be changed in any other way. It makes the strapping pin values available during the entire chip operation, and the pins are freed up to be used as regular IO pins after reset. For details on Chip Reset, see ESP32-C3 Technical Reference Manual > Chapter Reset and Clock.

The timing of signals connected to the strapping pins should adhere to the setup time and hold time specifications in Table 4-2 and Figure 4-1.

 t_H

ParameterDescriptionMin (ms) t_{SU} Setup time is the time reserved for the power rails to stabilize before the CHIP_EN pin is pulled high to activate the chip.Hold time is the time reserved for the chip to read the strapping

pin values after CHIP_EN is already high and before these pins

start operating as regular IO pins.

Table 4-2. Description of Timing Parameters for the Strapping Pins

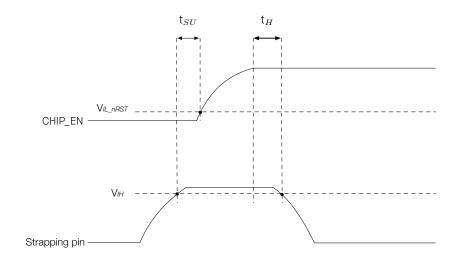


Figure 4-1. Visualization of Timing Parameters for the Strapping Pins

4.1 Chip Boot Mode Control

GPIO2, GPIO8, and GPIO9 control the boot mode after the reset is released. See Table 4-3 *Chip Boot Mode Control*.

Table 4-3. Chip Boot Mode Control

Boot Mode	GPI02 ²	GPI08	GPI09
SPI boot mode	1	Any value	1
Joint download boot mode ³	1	1	0

¹ **Bold** marks the default value and configuration.

- USB-Serial-JTAG Download Boot
- UART Download Boot

In SPI Boot mode, the ROM bootloader loads and executes the program from SPI flash to boot the system.

3

² GPIO2 actually does not determine SPI Boot and Joint Download Boot mode, but it is recommended to pull this pin up due to glitches.

³ Joint Download Boot mode supports the following download methods:

In Joint Download Boot mode, users can download binary files into flash using UARTO or USB interface. It is also possible to download binary files into SRAM and execute it from SRAM.

In addition to SPI Boot and Joint Download Boot modes, ESP32-C3 also supports SPI Download Boot mode. For details, please see ESP32-C3 Technical Reference Manual > Chapter Chip Boot Control.

4.2 **ROM Messages Printing Control**

During the boot process, the messages by the ROM code can be printed to:

- (Default) UARTO and USB Serial/JTAG controller
- UARTO
- USB Serial/JTAG controller

EFUSE UART PRINT CONTROL and GPIO8 control ROM messages printing to **UARTO** as shown in Table 4-4 UARTO ROM Message Printing Control.

UARTO ROM Code Printing	EFUSE_UART_PRINT_CONTROL	GPI08
	0	Ignored
Enabled	1	0
	2	1
	1	1
Disabled	2	0
	3	Ignored

Table 4-4. UARTO ROM Message Printing Control

EFUSE USB PRINT CHANNEL controls the printing to USB Serial/JTAG controller as shown in Table 4-5 USB Serial/JTAG ROM Message Printing Control.

Table 4-5. USB Serial/JTAG ROM Message Printing Control

USB Serial/JTAG ROM Code Printing	EFUSE_DIS_USB_SERIAL_JTAG ²	EFUSE_USB_PRINT_CHANNEL
Enabled	0	0
Disabled	0	1
Disabled	1	Ignored

¹ **Bold** marks the default value and configuration.

Chip Power-up and Reset

Once the power is supplied to the chip, its power rails need a short time to stabilize. After that, CHIP_EN - the pin used for power-up and reset - is pulled high to activate the chip. For information on CHIP_EN as well as power-up and reset timing, see Figure 4-2 and Table 4-6.

¹ **Bold** marks the default value and configuration.

 $^{^{2}}$ EFUSE DIS USB SERIAL_JTAG controls whether to disable USB Serial/JTAG.

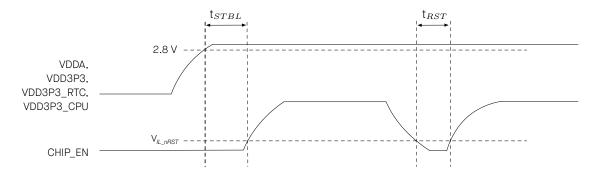


Figure 4-2. Visualization of Timing Parameters for Power-up and Reset

Table 4-6. Description of Timing Parameters for Power-up and Reset

Parameter	Description	Min (μs)
	Time reserved for the power rails of VDDA, VDD3P3,	
t_{STBL}	VDD3P3_RTC, and VDD3P3_CPU to stabilize before the CHIP_EN	50
	pin is pulled high to activate the chip	
+	Time reserved for CHIP_EN to stay below V_{IL_nRST} to reset the	F0
t_{RST}	chip (see Table 6-3)	50

5 Peripherals

5.1 Peripheral Overview

ESP32-C3 integrates a rich set of peripherals including SPI, UART, I2C, I2S, remote control peripheral, LED PWM controller, TWAI® controller, USB Serial/JTAG controller, temperature sensor, SAR ADC

To learn more about on-chip components, please refer to <u>ESP32-C3 Series Datasheet</u> > Section Functional Description.

Note:

The content below is sourced from <u>ESP32-C3 Series Datasheet</u> > Section *Peripherals*. Some information may not be applicable to ESP32-C3-WROOM-O2 and ESP32-C3-WROOM-O2U as not all the IO signals are exposed on the module. To learn more about peripheral signals, please refer to <u>ESP32-C3 Technical Reference Manual</u> > Section *Peripheral Signal List*.

5.2 Peripheral Description

This section describes the chip's peripheral capabilities, covering connectivity interfaces and on-chip sensors that extend its functionality.

5.2.1 Connectivity Interface

This subsection describes the connectivity interfaces on the chip that enable communication and interaction with external devices and networks.

5.2.1.1 UART Controller

ESP32-C3 has two UART interfaces, i.e. UARTO and UART1, which support IrDA and asynchronous communication (RS232 and RS485) at a speed of up to 5 Mbps. The UART controller provides hardware flow control (CTS and RTS signals) and software flow control (XON and XOFF). Both UART interfaces connect to GDMA via UHCIO, and can be accessed by the GDMA controller or directly by the CPU.

For details, see ESP32-C3 Technical Reference Manual > Chapter UART Controller (UART, LP_UART).

Pin Assignment

The pins connected to transmit and receive signals (UOTXD and UORXD) for **UARTO** are multiplexed with GPIO21 ~ GPIO20 via IO MUX. Other signals can be routed to any GPIOs via the GPIO matrix.

For more information about the pin assignment, see <u>ESP32-C3 Series Datasheet</u> > Section *IO Pins* and <u>ESP32-C3 Technical Reference Manual</u> > Chapter *IO MUX and GPIO Matrix*.

5.2.1.2 SPI Controller

ESP32-C3 has the following SPI interfaces:

- SPIO used by ESP32-C3's GDMA controller and cache to access in-package or off-package flash
- SPI1 used by the CPU to access in-package or off-package flash

• SPI2 is a general purpose SPI controller with access to a DMA channel allocated by the GDMA controller

Features of SPIO and SPI1

- Supports Single SPI, Dual SPI, and Quad SPI, QPI modes
- Configurable clock frequency with a maximum of 120 MHz in Single Transfer Rate (STR) mode
- Data transmission is in bytes

Features of SPI2

- Supports operation as a master or slave
- Connects to a DMA channel allocated by the GDMA controller
- Supports Single SPI, Dual SPI, and Quad SPI, QPI
- Configurable clock polarity (CPOL) and phase (CPHA)
- Configurable clock frequency
- Data transmission is in bytes
- Configurable read and write data bit order: most-significant bit (MSB) first, or least-significant bit (LSB) first
- As a master
 - Supports 2-line full-duplex communication with clock frequency up to 80 MHz
 - Supports 1-, 2-, 4-line half-duplex communication with clock frequency up to 80 MHz
 - Provides six SPI_CS pins for connection with six independent SPI slaves
 - Configurable CS setup time and hold time
- As a slave
 - Supports 2-line full-duplex communication with clock frequency up to 60 MHz
 - Supports 1-, 2-, 4-line half-duplex communication with clock frequency up to 60 MHz

For details, see ESP32-C3 Technical Reference Manual > Chapter SPI Controller (SPI).

Pin Assignment

For SPIO/1, the pins are multiplexed with GPIO12 ~ GPIO17 via the IO MUX.

For SPI2, the pins are multiplexed with GPI02, GPI04 \sim GPI07, GPI010, and JTAG interface via the IO MUX.

For more information about the pin assignment, see <u>ESP32-C3 Series Datasheet</u> > Section *IO Pins* and <u>ESP32-C3 Technical Reference Manual</u> > Chapter *IO MUX and GPIO Matrix*.

5.2.1.3 I2C Controller

ESP32-C3 has an I2C bus interface which is used for I2C master mode or slave mode, depending on your configuration. The I2C interface supports:

- standard mode (100 Kbit/s)
- fast mode (400 Kbit/s)
- up to 800 Kbit/s (constrained by SCL and SDA pull-up strength)
- 7-bit and 10-bit addressing mode
- double addressing mode
- 7-bit broadcast address

For details, see ESP32-C3 Technical Reference Manual > Chapter I2C Controller (I2C).

Pin Assignment

The pins for I2C can be chosen from any GPIOs via the GPIO Matrix.

For more information about the pin assignment, see <u>ESP32-C3 Series Datasheet</u> > Section *IO Pins* and <u>ESP32-C3 Technical Reference Manual</u> > Chapter *IO MUX and GPIO Matrix*.

5.2.1.4 I2S Controller

ESP32-C3 includes a standard I2S interface. This interface can operate as a master or a slave in full-duplex mode or half-duplex mode, and can be configured for 8-bit, 16-bit, 24-bit, or 32-bit serial communication. BCK clock frequency, from 10 kHz up to 40 MHz, is supported.

The I2S interface connects to the GDMA controller. The interface supports TDM PCM, TDM MSB alignment, TDM standard, and PDM standard.

For details, see ESP32-C3 Technical Reference Manual > Chapter I2S Controller (I2S).

Pin Assignment

The pins for the I2S Controller can be chosen from any GPIOs via the GPIO Matrix.

For more information about the pin assignment, see <u>ESP32-C3 Series Datasheet</u> > Section *IO Pins* and <u>ESP32-C3 Technical Reference Manual</u> > Chapter *IO MUX and GPIO Matrix*.

5.2.1.5 USB Serial/JTAG Controller

ESP32-C3 integrates a USB Serial/JTAG controller. This controller has the following features:

- CDC-ACM virtual serial port and JTAG adapter functionality
- USB 2.0 full speed compliant, capable of up to 12 Mbit/s transfer speed (Note that this controller does not support the faster 480 Mbit/s high-speed transfer mode)
- programming in-package/off-package flash
- CPU debugging with compact JTAG instructions
- a full-speed USB PHY integrated in the chip

For details, see <u>ESP32-C3 Technical Reference Manual</u> > Chapter USB Serial/JTAG Controller (USB_SERIAL_JTAG).

Pin Assignment

The pins for the USB Serial/JTAG Controller are multiplexed with GPIO18 ~ GPIO19.

For more information about the pin assignment, see ESP32-C3 Series Datasheet > Section IO Pins and ESP32-C3 Technical Reference Manual > Chapter IO MUX and GPIO Matrix.

5.2.1.6 Two-wire Automotive Interface

ESP32-C3 has a TWAI® controller with the following features:

- compatible with ISO 11898-1 protocol (CAN Specification 2.0)
- standard frame format (11-bit ID) and extended frame format (29-bit ID)
- bit rates from 1 Kbit/s to 1 Mbit/s
- multiple modes of operation: Normal, Listen Only, and Self-Test (no acknowledgment required)
- 64-byte receive FIFO
- acceptance filter (single and dual filter modes)
- error detection and handling: error counters, configurable error interrupt threshold, error code capture, arbitration lost capture

For details, see ESP32-C3 Technical Reference Manual > Chapter Two-wire Automotive Interface.

Pin Assignment

The pins for the Two-wire Automotive Interface can be chosen from any GPIOs via the GPIO Matrix.

For more information about the pin assignment, see ESP32-C3 Series Datasheet > Section IO Pins and ESP32-C3 Technical Reference Manual > Chapter IO MUX and GPIO Matrix.

LED PWM Controller 5.2.1.7

The LED PWM controller can generate independent digital waveform on six channels. The LED PWM controller:

- Can generate digital waveform with configurable periods and duty cycle. The resolution of duty cycle can be up to 14 bits.
- Has multiple clock sources, including APB clock and external main crystal clock.
- Can operate when the CPU is in Light-sleep mode.
- Supports gradual increase or decrease of duty cycle, which is useful for the LED RGB color-gradient generator.

For details, see <u>ESP32-C3 Technical Reference Manual</u> > Chapter LED PWM Controller.

Pin Assignment

The pins for the LED PWM Controller can be chosen from any GPIOs via the GPIO Matrix.

For more information about the pin assignment, see ESP32-C3 Series Datasheet > Section IO Pins and ESP32-C3 Technical Reference Manual > Chapter IO MUX and GPIO Matrix.

5.2.1.8 Remote Control Peripheral

The Remote Control Peripheral (RMT) supports two channels of infrared remote transmission and two channels of infrared remote reception. By controlling pulse waveform through software, it supports various infrared and other single wire protocols. All four channels share a 192 × 32-bit memory block to store transmit or receive waveform.

For more details, see ESP32-C3 Technical Reference Manual > Chapter Remote Control Peripheral (RMT).

Pin Assignment

The pins for the Remote Control Peripheral can be chosen from any GPIOs via the GPIO Matrix.

For more information about the pin assignment, see ESP32-C3 Series Datasheet > Section IO Pins and ESP32-C3 Technical Reference Manual > Chapter IO MUX and GPIO Matrix.

5.2.2 Analog Signal Processing

This subsection describes components on the chip that sense and process real-world data.

5.2.2.1 SAR ADC

ESP32-C3 integrates two 12-bit SAR ADCs.

- ADC1 supports measurements on 5 channels, and is factory-calibrated.
- ADC2 supports measurements on 1 channel, and is not factory-calibrated.

Note:

ADC2 of some chip revisions is not operable. For details, please refer to ESP32-C3 Series SoC Errata.

For more details, see ESP32-C3 Technical Reference Manual > Chapter On-Chip Sensors and Analog Signal Processing.

Pin Assignment

The pins for the SAR ADC are multiplexed with GPIOO ~ GPIO5, JTAG interface, SPI2 interface, and pins for external crystal or oscillator.

For more information about the pin assignment, see ESP32-C3 Series Datasheet > Section IO Pins and ESP32-C3 Technical Reference Manual > Chapter IO MUX and GPIO Matrix.

5.2.2.2 Temperature Sensor

The temperature sensor generates a voltage that varies with temperature. The voltage is internally converted via an ADC into a digital value.

The temperature sensor has a range of -40 °C to 125 °C. It is designed primarily to sense the temperature changes inside the chip. The temperature value depends on factors like microcontroller clock frequency or I/O load. Generally, the chip's internal temperature is higher than the operating ambient temperature.

Electrical Characteristics

Absolute Maximum Ratings 6.1

Stresses above those listed in Table 6-1 Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under Table 6-2 Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Table 6-1. Absolute Maximum Ratings

Symbol	Parameter	Min	Max	Unit
VDD33	Power supply voltage	-0.3	3.6	V
T_{STORE}	Storage temperature	-40	105	°C

Recommended Operating Conditions

Table 6-2. Recommended Operating Conditions

Symbol	Parameter		Min	Тур	Max	Unit
VDD33	Power supply voltage		3.0	3.3	3.6	V
$ V_{VDD} $	Current delivered by external power supply		0.5	_	_	Α
т.	Operating ambient temperature 85 °C version 105 °C version		-40		85	°C
			-40	_	105	

DC Characteristics (3.3 V, 25 °C)

Table 6-3. DC Characteristics (3.3 V, 25 °C)

Parameter	Description	Min	Тур	Max	Unit
C_{IN}	Pin capacitance	_	2	_	pF
V_{IH}	High-level input voltage	0.75 × VDD ¹	_	VDD ¹ + 0.3	V
V_{IL}	Low-level input voltage	-0.3	_	0.25 × VDD ¹	V
$ _{IH}$	High-level input current	_	_	50	nA
_{IL}	Low-level input current	_	_	50	nA
V _{OH} 2	High-level output voltage	0.8 × VDD 1	_	_	V
V _{OL} 2	Low-level output voltage	_	_	0.1 × VDD ¹	V
	High-level source current (VDD ¹ = 3.3 V,		40		mA
$ _{OH}$	V _{OH} >= 2.64 V, PAD_DRIVER = 3)	_	40	_	
	Low-level sink current (VDD 1 = 3.3 V, V_{OL} =		28		mA
$ \cdot _{OL}$	0.495 V, PAD_DRIVER = 3)	_	20	_	IIIA
R_{PU}	Internal weak pull-up resistor	_	45	_	kΩ
R_{PD}	Internal weak pull-down resistor	_	45	_	kΩ
\/	Chip reset release voltage CHIP_EN voltage	0.75 × VDD ¹	_	VDD ¹ + 0.3	V
V_{IH_nRST}	is within the specified range)	0.75 ^ VDD		VDD + 0.3	V

\bigvee_{IL_nRST}	Chip reset voltage (CHIP_EN voltage is within the specified range)	-0.3	_	0.25 × VDD ¹	V	
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¹ VDD – voltage from a power pin of a respective power domain.

6.4 Current Consumption Characteristics

6.4.1 Current Consumption in Active Mode

The current consumption measurements are taken with a 3.3 V supply at 25 °C ambient temperature.

TX current consumption is rated at a 100% duty cycle.

RX current consumption is rated when the peripherals are disabled and the CPU idle.

Table 6-4. Current Consumption for Wi-Fi (2.4 GHz) in Active Mode

Work mode Description		Peak (mA)	
	TX RX	802.11b, 1 Mbps, @20.5 dBm	345
		802.11g, 54 Mbps, @18 dBm	285
Active (RF working)		802.11n, HT20, MCS7, @17.5 dBm	280
		802.11n, HT40, MCS7, @17 dBm	280
		802.11b/g/n, HT20	82
		802.11n, HT40	84

Note:

The content below is excerpted from Section Power Consumption in Other Modes in <u>ESP32-C3 Series Datasheet</u>.

6.4.2 Current Consumption in Other Modes

Table 6-5. Current Consumption in Modem-sleep Mode

	CPU Frequency		Тур		
Mode	(MHz)	Description	All Peripherals Clocks	All Peripherals Clocks	
	(IVITZ)		Disabled (mA)	Enabled (mA) ¹	
		CPU is running	23	28	
Modem-sleep ² ,		CPU is idle	16	21	
Modern-sieeb 7		CPU is running	17	22	
	80	CPU is idle	13	18	

¹ In practice, the current consumption might be different depending on which peripherals are enabled.

 $^{^{2}}$ V_{OH} and V_{OL} are measured using high-impedance load.

² In Modem-sleep mode, Wi-Fi is clock gated.

³ In Modem-sleep mode, the consumption might be higher when accessing flash. For a flash rated at 80 Mbit/s, in SPI 2-line mode the consumption is 10 mA.

Table 6-6. Current Consumption in Low-Power Modes

Mode	Description	Typ (μ A)
Light-sleep	VDD_SPI and Wi-Fi are powered down, and all GPIOs are high-impedance	130
Deep-sleep	RTC timer + RTC memory	5
Power off	CHIP_EN is set to low level, the chip is powered off	1

Memory Specifications 6.5

The data below is sourced from the memory vendor datasheet. These values are guaranteed through design and/or characterization but are not fully tested in production. Devices are shipped with the memory erased.

Table 6-7. Flash Specifications

Parameter	Description	Min	Тур	Max	Unit
VCC	Power supply voltage (1.8 V)	1.65	1.80	2.00	V
VCC	Power supply voltage (3.3 V)	2.7	3.3	3.6	V
F_C	Maximum clock frequency	80	_	_	MHz
_	Program/erase cycles	100,000	_	_	cycles
T_{RET}	Data retention time	20	_	_	years
T_{PP}	Page program time	_	0.8	5	ms
T_{SE}	Sector erase time (4 KB)	_	70	500	ms
T_{BE1}	Block erase time (32 KB)	_	0.2	2	S
T_{BE2}	Block erase time (64 KB)	_	0.3	3	S
	Chip erase time (16 Mb)	_	7	20	S
	Chip erase time (32 Mb)	_	20	60	S
T_{CE}	Chip erase time (64 Mb)	_	25	100	S
	Chip erase time (128 Mb)	_	60	200	S
	Chip erase time (256 Mb)	_	70	300	S

7 RF Characteristics

This section contains tables with RF characteristics of the Espressif product.

The RF data is measured at the antenna port, where RF cable is connected, including the front-end loss. The external antennas used for the tests on the modules with external antenna connectors have an impedance of Ω .

Devices should operate in the center frequency range allocated by regional regulatory authorities. The target center frequency range and the target transmit power are configurable by software. See <u>ESP RF Test Tool and Test Guide</u> for instructions.

Unless otherwise stated, the RF tests are conducted with a 3.3 V (±5%) supply at 25 °C ambient temperature.

7.1 Wi-Fi Radio

Table 7-1. Wi-Fi RF Characteristics

Name	Description
Center frequency range of operating channel	2412 ~ 2484 MHz
Wi-Fi wireless standard	IEEE 802.11b/g/n

7.1.1 Wi-Fi RF Transmitter (TX) Characteristics

Table 7-2. TX Power with Spectral Mask and EVM Meeting 802.11 Standards

Rate	Min	Тур	Max
Rate	(dBm)	(dBm)	(dBm)
802.11b, 1 Mbps	_	20.5	_
802.11b, 11 Mbps	_	20.5	_
802.11g, 6 Mbps	_	20.0	_
802.11g, 54 Mbps	_	18.0	_
802.11n, HT20, MCS0	_	19.0	_
802.11n, HT20, MCS7	_	17.5	_
802.11n, HT40, MCS0	_	18.5	_
802.11n, HT40, MCS7	_	17.0	_

Table 7-3. TX EVM Test¹

Rate	Min (dB)	Typ (dB)	Limit (dB)
802.11b, 1 Mbps, @20.5 dBm	_	-24.5	-10
802.11b, 11 Mbps, @20.5 dBm	_	-25.0	-10
802.11g, 6 Mbps, @20 dBm	_	-23.0	-5
802.11g, 54 Mbps, @18 dBm	_	-28.0	-25

Cont'd on next page

Table 7-3 – cont'd from previous page

Rate	Min (dB)	Typ (dB)	Limit (dB)
802.11n, HT20, MCS0, @19 dBm	_	-23.5	-5
802.11n, HT20, MCS7, @17.5 dBm	_	-29.5	-27
802.11n, HT40, MCS0, @18.5 dBm	_	-26.5	-5
802.11n, HT40, MCS7, @17 dBm	_	-29.5	-27

¹ EVM is measured at the corresponding typical TX power provided in Table 7-2 TX Power with Spectral Mask and EVM Meeting 802.11 Standards above.

7.1.2 Wi-Fi RF Receiver (RX) Characteristics

For RX tests, the PER (packet error rate) limit is 8% for 802.11b, and 10% for 802.11g/n/ax.

Table 7-4. RX Sensitivity

Poto	Min	Тур	Max
Rate	(dBm)	(dBm)	(dBm)
802.11b, 1 Mbps	_	-98.0	_
802.11b, 2 Mbps	_	-96.0	_
802.11b, 5.5 Mbps	_	-93.0	_
802.11b, 11 Mbps	_	-88.6	_
802.11g, 6 Mbps	_	-93.0	_
802.11g, 9 Mbps	_	-92.0	_
802.11g, 12 Mbps	_	-90.8	_
802.11g, 18 Mbps	_	-88.4	_
802.11g, 24 Mbps	_	-85.4	_
802.11g, 36 Mbps	_	-82.0	_
802.11g, 48 Mbps	_	-78.0	_
802.11g, 54 Mbps	_	-76.4	_
802.11n, HT20, MCS0	_	-93.0	_
802.11n, HT20, MCS1	_	-90.8	_
802.11n, HT20, MCS2	_	-88.2	_
802.11n, HT20, MCS3	_	-84.6	_
802.11n, HT20, MCS4	_	-81.4	_
802.11n, HT20, MCS5	_	-77.4	_
802.11n, HT20, MCS6	_	-75.4	_
802.11n, HT20, MCS7	_	-74.4	_
802.11n, HT40, MCS0	_	-90.0	_
802.11n, HT40, MCS1	_	-87.6	_
802.11n, HT40, MCS2	_	-84.8	_
802.11n, HT40, MCS3	_	-81.8	_
802.11n, HT40, MCS4	_	-78.4	_
802.11n, HT40, MCS5	_	-74.4	_

Cont'd on next page

Table 7-4 - cont'd from previous page

Rate	Min (dBm)	Typ (dBm)	Max (dBm)
802.11n, HT40, MCS6	_	-72.6	_
802.11n, HT40, MCS7	_	-71.2	_

Table 7-5. Maximum RX Level

Rate	Min (dBm)	Typ (dBm)	Max (dBm)
802.11b, 1 Mbps	_	5	_
802.11b, 11 Mbps	_	5	_
802.11g, 6 Mbps	_	5	_
802.11g, 54 Mbps	_	0	_
802.11n, HT20, MCS0	_	5	_
802.11n, HT20, MCS7	_	0	_
802.11n, HT40, MCS0	_	5	_
802.11n, HT40, MCS7	_	0	_

Table 7-6. RX Adjacent Channel Rejection

Rate	Min (dB)	Typ (dB)	Max (dB)
802.11b, 1 Mbps	_	35	_
802.11b, 11 Mbps	_	35	
802.11g, 6 Mbps	_	31	
802.11g, 54 Mbps	_	20	
802.11n, HT20, MCS0	_	31	
802.11n, HT20, MCS7	_	16	_
802.11n, HT40, MCS0	_	25	_
802.11n, HT40, MCS7	_	11	

7.2 Bluetooth 5 (LE) Radio

Table 7-7. Bluetooth LE RF Characteristics

Name	Description
Center frequency range of operating channel	2402 ~ 2480 MHz
RF transmit power range	-24.0 ~ 20.0 dBm

7.2.1 Bluetooth LE RF Transmitter (TX) Characteristics

Table 7-8. Bluetooth LE - Transmitter Characteristics - 1 Mbps

Parameter	Description	Min	Тур	Max	Unit
	F = F0 ± 2 MHz	_	-37.62	_	dBm
In-band emissions	$F = FO \pm 3 MHz$	_	-41.95	_	dBm
	F = F0 ± > 3 MHz	_	-44.48	_	dBm
	$\Delta f 1_{avg}$	_	245.00	_	kHz
Modulation characteristics	$\Delta f 2_{ ext{max}}$	_	208.00	_	kHz
	$\Delta f 2_{\text{avg}}/\Delta f 1_{\text{avg}}$	_	0.93	_	_
Carrier frequency offset	_	_	-9.00	_	kHz
	$ f_0 - f_n _{n=2, 3, 4,k}$	_	1.17	_	kHz
Carrier frequency drift	$ f_1 - f_0 $	_	0.30	_	kHz
	$ f_{n}-f_{n-5} _{n=6, 7, 8,k}$	_	4.90	_	kHz

Table 7-9. Bluetooth LE - Transmitter Characteristics - 2 Mbps

Parameter	Description	Min	Тур	Max	Unit
	$F = FO \pm 4 MHz$	_	-43.55	_	dBm
In-band emissions	$F = FO \pm 5 MHz$	_	-45.26	_	dBm
	F = F0 ± > 5 MHz	_	-47.00	_	dBm
	$\Delta f 1_{avg}$	_	497.00	_	kHz
Modulation characteristics	$\Delta f2_{ ext{max}}$	_	398.00	_	kHz
	$\Delta f 2_{\text{avg}}/\Delta f 1_{\text{avg}}$	_	0.95	_	_
Carrier frequency offset	_	_	-9.00	_	kHz
	$ f_0 - f_n _{n=2, 3, 4,k}$	_	0.46	_	kHz
Carrier frequency drift	$ f_1-f_0 $	_	0.70	_	kHz
	$ f_{n}-f_{n-5} _{n=6, 7, 8,k}$	_	6.80	_	kHz

Table 7-10. Bluetooth LE - Transmitter Characteristics - 125 Kbps

Parameter	Description	n Min Typ		Max	Unit
	F = F0 ± 2 MHz	_	-37.90	_	dBm
In-band emissions	F = F0 ± 3 MHz	_	-41.00	_	dBm
	F = F0 ± > 3 MHz	_	-42.50	_	dBm
Modulation characteristics	$\Deltaf1_{ ext{avg}}$	_	252.00	_	kHz
Modulation characteristics	$\Deltaf1_{max}$	_	200.00	_	kHz
Carrier frequency offset	_	_	-13.70	_	kHz
	$ f_0 - f_n _{n=1, 2, 3,k}$	_	1.52	_	kHz
Carrier frequency drift	$ f_0 - f_3 $	_	0.65	_	kHz
	$ f_{n}-f_{n-3} _{n=7, 8, 9,k}$	_	0.70	_	kHz

Table 7-11. Bluetooth LE - Transmitter Characteristics - 500 Kbps

Parameter	Description	Min	Тур	Max	Unit
	F = FO ± 2 MHz		-37.90	_	dBm
In-band emissions	$F = FO \pm 3 MHz$	_	-41.30	_	dBm
	$F = FO \pm > 3 MHz$		-42.80	-	dBm
Modulation characteristics	$\Delta~f2_{ ext{avg}}$	_	220.00	_	kHz
Modulation characteristics	$\Delta f2_{ ext{max}}$	_	205.00	_	kHz
Carrier frequency offset		_	-11.90	_	kHz
	$ f_0 - f_n _{n=1, 2, 3,k}$	_	1.37	_	kHz
Carrier frequency drift	$ f_0 - f_3 $	_	1.09	_	kHz
	$ f_{n}-f_{n-3} _{n=7, 8, 9,k}$	_	0.51	_	kHz

7.2.2 Bluetooth LE RF Receiver (RX) Characteristics

Table 7-12. Bluetooth LE - Receiver Characteristics - 1 Mbps

Parameter	Description	Min	Тур	Max	Unit
Sensitivity @30.8% PER	_	_	-97	_	dBm
Maximum received signal @30.8% PER	_	_	10	_	dBm
Co-channel C/I	_	_	7	_	dB
	F = FO + 1 MHz	_	-4	_	dB
	F = FO – 1 MHz	_	-4	_	dB
Adjacent channel selectivity C/I	F = F0 + 2 MHz	_	-29	_	dB
Adjacent channel selectivity C/1	F = F0 - 2 MHz	_	-31	_	dB
	F ≥ F0 + 3 MHz	_	-33	_	dB
	F ≤ F0 − 3 MHz	_	-35	_	dB
	F ≥ FO + 4 MHz	_	-35	_	dB
	F ≤ FO − 4 MHz	_	-37	_	dB
Image frequency	_	_	-35	_	dB
Adjacent channel to image frequency	$F = F_{image} + 1 MHz$	_	-40	_	dB
Adjacent channel to image frequency	$F = F_{image} - 1 \text{ MHz}$	_	-33	_	dB
	30 MHz ~ 2000 MHz	_	-6	_	dBm
Out-of-band blocking performance	2003 MHz ~ 2399 MHz	_	-26	_	dBm
	2484 MHz ~ 2997 MHz	_	-25	_	dBm
	3000 MHz ~ 12.75 GHz	_	-5	_	dBm
Intermodulation	_	_	-30	_	dBm

Table 7-13. Bluetooth LE - Receiver Characteristics - 2 Mbps

Parameter	Description	Min	Тур	Max	Unit
Sensitivity @30.8% PER	_	_	-93	_	dBm
Maximum received signal @30.8% PER	_	_	5	_	dBm
Co-channel C/I	_	_	10	_	dB
	F = FO + 2 MHz	_	-8	_	dB
	F = FO - 2 MHz	_	-7	_	dB
Adjacent channel selectivity C/I	F = FO + 4 MHz	_	-32	_	dB
Adjacent charmer selectivity 6/1	F = FO - 4 MHz	_	-34	_	dB
	$F \ge FO + 6 MHz$	_	-39	_	dB
	F ≤ F0 − 6 MHz	_	-39	-	dB
Image frequency	_	_	-32		dB
Adjacent channel to image frequency	$F = F_{image} + 2 \text{ MHz}$	_	-39	_	dB
Adjacent channel to image frequency	$F = F_{image} - 2 \text{ MHz}^{(2)}$	_	-8	_	dB
	30 MHz ~ 2000 MHz	_	-12	_	dBm
Out-of-band blocking performance	2003 MHz ~ 2399 MHz	_	-30	_	dBm
out-or-band blocking performance	2484 MHz ~ 2997 MHz	_	-28	_	dBm
	3000 MHz ~ 12.75 GHz	_	-6	_	dBm
Intermodulation	_	_	-29	_	dBm

Table 7-14. Bluetooth LE - Receiver Characteristics - 125 Kbps

Parameter	Description	Min	Тур	Max	Unit
Sensitivity @30.8% PER	_	_	-105 -		dBm
Maximum received signal @30.8% PER	_	_	10	_	dBm
Co-channel C/I	_	_	2	_	dB
	F = FO + 1 MHz	_	-6	_	dB
	F = FO – 1 MHz	_	-4	_	dB
Adjacent channel coloctivity C/I	F = FO + 2 MHz	_	-33	_	dB
Adjacent channel selectivity C/I	F = FO - 2 MHz	_	-41	_	dB
	F ≥ F0 + 3 MHz	_	-37	_	dB
	F ≤ F0 − 3 MHz	_	-46	_	dB
	$F \ge FO + 4 MHz$	_	-40	_	dB
	F ≤ FO − 4 MHz	_	-49	_	dB
Image frequency	_	_	-40		dB
Adjacent channel to image frequency	$F = F_{image} + 1 MHz$	_	-46	_	dB
Adjacent channel to image frequency	F = F _{image} – 1 MHz	_	-37	_	dB

Table 7-15. Bluetooth LE - Receiver Characteristics - 500 Kbps

Parameter	Description	Min	Тур	Max	Unit
Sensitivity @30.8% PER	_	_	-101	_	dBm
Maximum received signal @30.8% PER	_	_	10	_	dBm

Cont'd on next page

Table 7-15 – cont'd from previous page

Parameter	Description	Min	Тур	Max	Unit
Co-channel C/I	_	_	3		dB
	F = FO + 1 MHz	_	-6	_	dB
	F = FO – 1 MHz	_	-7	_	dB
Adjacent channel coloctivity C/I	F = F0 + 2 MHz	_	-34	_	dB
Adjacent channel selectivity C/I	F = F0 - 2 MHz	_	-37	_	dB
	F ≥ F0 + 3 MHz	_	-38	_	dB
	F ≤ F0 − 3 MHz	_	-40	_	dB
	$F \ge FO + 4 MHz$	_	-40	_	dB
	F ≤ FO − 4 MHz	_	-42	_	dB
Image frequency	_	_	-40	_	dB
Adjacent channel to image frequency	$F = F_{image} + 1 MHz$	_	-45		dB
Aujacent channel to inage nequency	$F = F_{image} - 1 \text{ MHz}$	_	-38	_	dB

 $| \infty |$

8 Module Schematics

This is the reference design of the module.

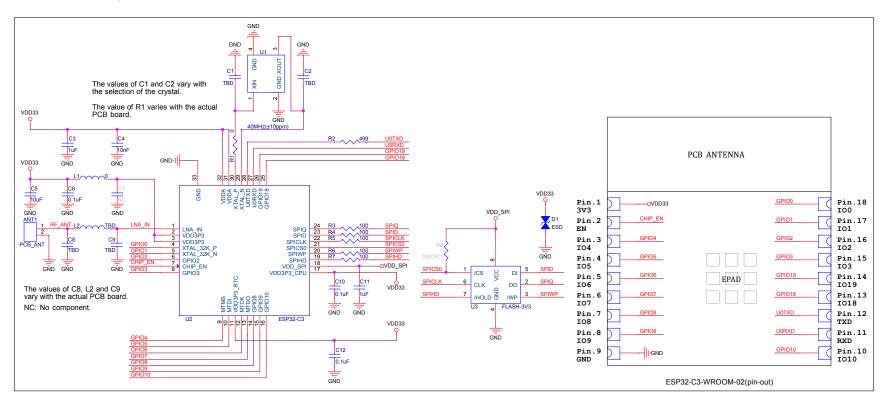


Figure 8-1. ESP32-C3-WROOM-02 Schematics

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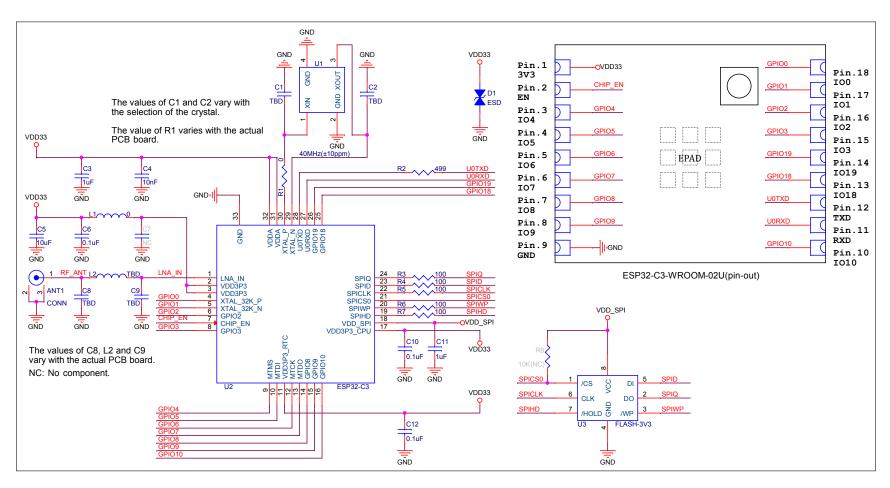


Figure 8-2. ESP32-C3-WROOM-02U Schematics

9 Peripheral Schematics

This is the typical application circuit of the module connected with peripheral components (for example, power supply, antenna, reset button, JTAG interface, and UART interface).

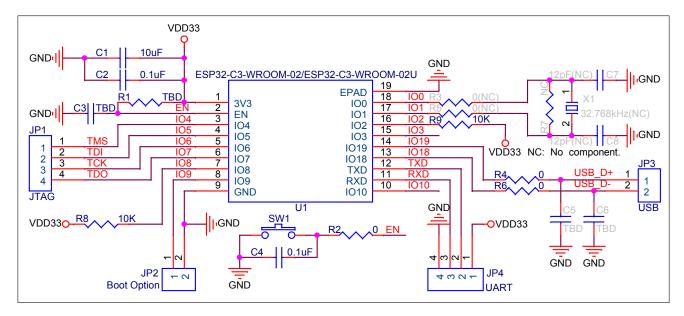


Figure 9-1. Peripheral Schematics

- Soldering the EPAD to the ground of the base board is not a must, however, it can optimize thermal performance. If you choose to solder it, please apply the correct amount of soldering paste. Too much soldering paste may increase the gap between the module and the baseboard. As a result, the adhesion between other pins and the baseboard may be poor.
- To ensure that the power supply to the ESP32-C3 chip is stable during power-up, it is advised to add an RC delay circuit at the EN pin. The recommended setting for the RC delay circuit is usually R = 10 k Ω and C = 1 μ F. However, specific parameters should be adjusted based on the power-up timing of the module and the power-up and reset sequence timing of the chip. For ESP32-C3's power-up and reset sequence timing diagram, please refer Section 4.3 *Chip Power-up and Reset*.
- UARTO is used to download firmware and log output. When using the AT firmware, note that the UART GPIO is already configured. It is recommended to use the default configuration. Please refer to ESP-AT User Guide for ESP32-C3 > Section Hardware Connection.

10 Physical Dimensions

10.1 Module Dimensions

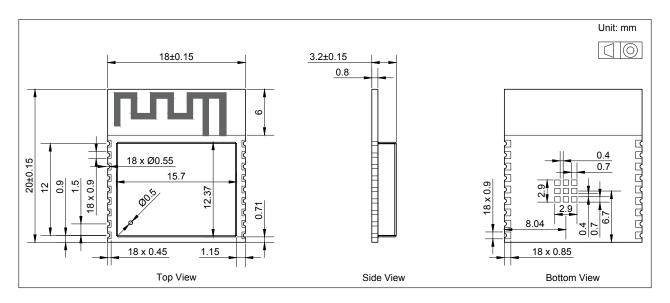


Figure 10-1. ESP32-C3-WROOM-02 Physical Dimensions

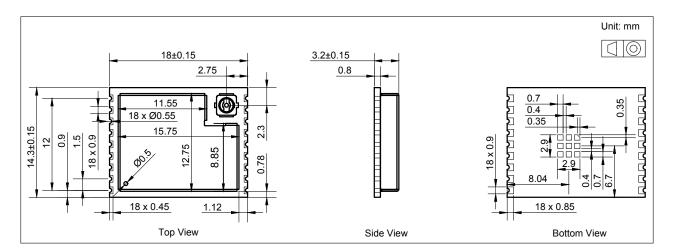


Figure 10-2. ESP32-C3-WROOM-02U Physical Dimensions

Note:

For information about tape, reel, and product marking, please refer to <u>ESP32-C3 Module Packaging Information</u>.

10.2 Dimensions of External Antenna Connector

ESP32-C3-WROOM-O2U uses the first generation external antenna connector as shown in Figure 10-3 *Dimensions of External Antenna Connector*. This connector is compatible with the following connectors:

- U.FL Series connector from Hirose
- MHF I connector from I-PEX
- AMC connector from Amphenol

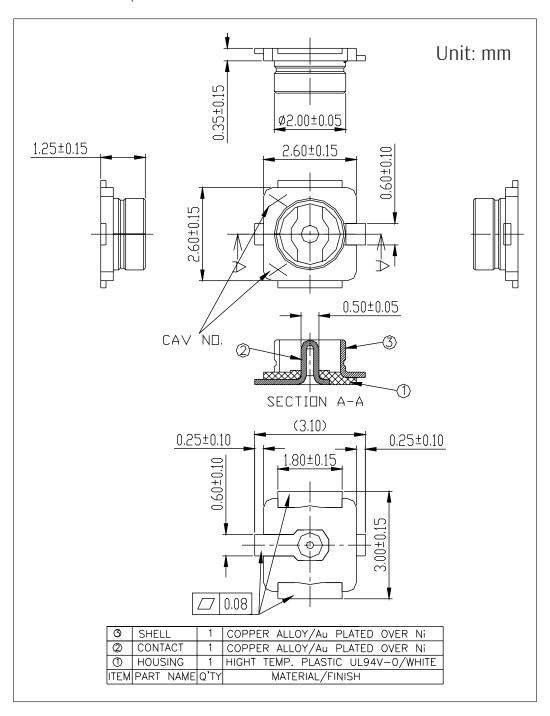


Figure 10-3. Dimensions of External Antenna Connector

The external antenna used for ESP32-C3-WROOM-O2U during certification testing is

- Certification except FCC: First generation monopole antenna, with material code TFPD05H08750011
- FCC: Glue stick antenna, with material code TFPD05H09170011

The module does not include an external antenna upon shipment. If needed, select a suitable external antenna based on the product's usage environment and performance requirements.

It is recommended to select an antenna that meets the following requirements:

- 2.4 GHz band
- 50 Ω impedance
- The maximum gain does not exceed the gain of the antenna used for certification, which is
 - Certification except FCC: 2.33 dBi
 - FCC: 1.57 dBi
- The connector matches the specifications shown in Figure 10-3 Dimensions of External Antenna Connector

Note:

If you use an external antenna of a different type or gain, additional testing, such as EMC, may be required beyond the existing antenna test reports for Espressif modules. Specific requirements depend on the certification type.

11 PCB Layout Recommendations

11.1 PCB Land Pattern

This section provides the following resources for your reference:

- Figures for recommended PCB land patterns with all the dimensions needed for PCB design. See Figure 11-1 ESP32-C3-WROOM-02 Recommended PCB Land Pattern and Figure 11-2 ESP32-C3-WROOM-02U Recommended PCB Land Pattern.
- Source files of recommended PCB land patterns to measure dimensions not covered in Figure 11-1 and Figure 11-2. You can view the source files for ESP32-C3-WROOM-02 and ESP32-C3-WROOM-02 with Autodesk Viewer.
- 3D models of <u>ESP32-C3-WROOM-O2</u> and <u>ESP32-C3-WROOM-O2U</u>. Please make sure that you download the 3D model file in .STEP format. Beware that some browsers might add .txt.

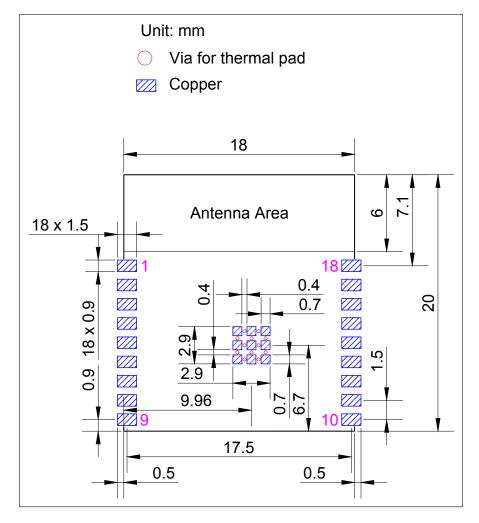


Figure 11-1. ESP32-C3-WROOM-02 Recommended PCB Land Pattern

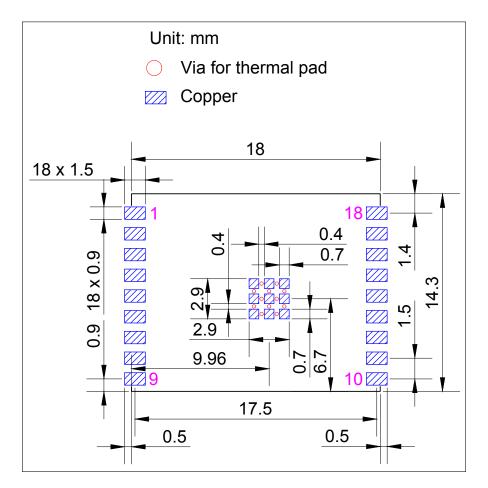


Figure 11-2. ESP32-C3-WROOM-02U Recommended PCB Land Pattern

Module Placement for PCB Design 11.2

If module-on-board design is adopted, attention should be paid while positioning the module on the base board. The interference of the base board on the module's antenna performance should be minimized.

For details about module placement for PCB design, please refer to ESP32-C3 Hardware Design Guidelines > Section General Principles of PCB Layout for Modules.

Product Handling 12

12.1 **Storage Conditions**

The products sealed in moisture barrier bags (MBB) should be stored in a non-condensing atmospheric environment of < 40 °C and 90%RH. The module is rated at the moisture sensitivity level (MSL) of 3.

After unpacking, the module must be soldered within 168 hours with the factory conditions 25±5 °C and 60%RH. If the above conditions are not met, the module needs to be baked.

Electrostatic Discharge (ESD) 12.2

• Human body model (HBM): ±2000 V • Charged-device model (CDM): ±500 V

Reflow Profile 12.3

Solder the module in a single reflow.

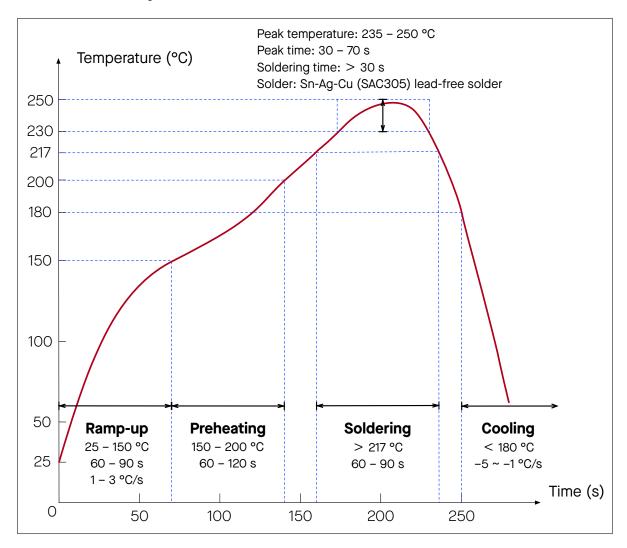


Figure 12-1. Reflow Profile

Ultrasonic Vibration 12.4

Avoid exposing Espressif modules to vibration from ultrasonic equipment, such as ultrasonic welders or ultrasonic cleaners. This vibration may induce resonance in the in-module crystal and lead to its malfunction or even failure. As a consequence, the module may stop working or its performance may deteriorate.

Datasheet Versioning

Datasheet Version	Status	Watermark	Definition
v0.1 ~ v0.5 (excluding v0.5)	Draft	Confidential	This datasheet is under development for products in the design stage. Specifications may change without prior notice.
v0.5 ~ v1.0 (excluding v1.0)	Preliminary release	Preliminary	This datasheet is actively updated for products in the verification stage. Specifications may change before mass production, and the changes will be documentation in the datasheet's Revision History.
v1.0 and higher	Official release	_	This datasheet is publicly released for products in mass production. Specifications are finalized, and major changes will be communicated via Product Change Notifications (PCN) .
Any version	_	Not Recommended for New Design (NRND) ¹	This datasheet is updated less frequently for products not recommended for new designs.
Any version	_	End of Life (EOL) ²	This datasheet is no longer matined for products that have reached end of life.

¹ Watermark will be added to the datasheet title page only when all the product variants covered by this datasheet are not recommended for new designs.

² Watermark will be added to the datasheet title page only when all the product variants covered by this datasheet have reached end of life.

Related Documentation and Resources

Related Documentation

- ESP32-C3 Series Datasheet Specifications of the ESP32-C3 hardware.
- ESP32-C3 Technical Reference Manual Detailed information on how to use the ESP32-C3 memory and peripherals.
- ESP32-C3 Hardware Design Guidelines Guidelines on how to integrate the ESP32-C3 into your hardware prod-
- ESP32-C3 Series SoC Errata Descriptions of known errors in ESP32-C3 series of SoCs.
- Certificates

https://espressif.com/en/support/documents/certificates

- ESP32-C3 Product/Process Change Notifications (PCN)
 https://espressif.com/en/support/documents/pcns?keys=ESP32-C3
- ESP32-C3 Advisories Information on security, bugs, compatibility, component reliability.
 https://espressif.com/en/support/documents/advisories?keys=ESP32-C3
- Documentation Updates and Update Notification Subscription https://espressif.com/en/support/download/documents

Developer Zone

- ESP-IDF Programming Guide for ESP32-C3 Extensive documentation for the ESP-IDF development framework.
- ESP-IDF and other development frameworks on GitHub.

https://github.com/espressif

- ESP32 BBS Forum Engineer-to-Engineer (E2E) Community for Espressif products where you can post questions, share knowledge, explore ideas, and help solve problems with fellow engineers.
 https://esp32.com/
- ESP-FAQ A summary document of frequently asked questions released by Espressif. https://espressif.com/projects/esp-faq/en/latest/index.html
- The ESP Journal Best Practices, Articles, and Notes from Espressif folks. https://blog.espressif.com/
- See the tabs SDKs and Demos, Apps, Tools, AT Firmware. https://espressif.com/en/support/download/sdks-demos

Products

- ESP32-C3 Series SoCs Browse through all ESP32-C3 SoCs. https://espressif.com/en/products/socs?id=ESP32-C3
- ESP32-C3 Series Modules Browse through all ESP32-C3-based modules.

https://espressif.com/en/products/modules?id=ESP32-C3

- ESP32-C3 Series DevKits Browse through all ESP32-C3-based devkits.
 - https://espressif.com/en/products/devkits?id=ESP32-C3
- ESP Product Selector Find an Espressif hardware product suitable for your needs by comparing or applying filters. https://products.espressif.com/#/product-selector?language=en

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https://espressif.com/en/contact-us/sales-questions

Revision History

Date	Version	Release notes
2025-07-14	∨1.6	 Added Section 4.3 Chip Power-up and Reset Added Section 6.5 Memory Specifications Section 9 Peripheral Schematics: Added a note about AT communication using UARTO Section 10.2 Dimensions of External Antenna Connector: Added the external antenna information for certification Added Datasheet Versioning
2025-04-14	V1.5	According to updates in Compatibility Advisory for ESP32-C3 Chip Revision v1.1, updated SRAM space in note 6 for Table ESP32-C3-WROOM-02U (CONN) Series Comparison
2024-09-19	∨1.4	 Deleted the ESP32-C3-WROOM-O2-N8 and ESP32-C3-WROOM-O2U-N8 variants, updated notes about customizing modules with 8 MB or 16 MB flash, and updated flash program/erase cycles, data retention time (note 4) and maximum clock frequency (note 7)in Table ESP32-C3-WROOM-O2 (ANT) Series Comparison¹ and Table ESP32-C3-WROOM-O2U (CONN) Series Comparison Improved the wording and structure of following sections: Updated Section "Strapping Pins" and renamed to 4 Boot Configurations Added Chapter 5 Peripherals Updated Table "Wi-Fi RF Standards" and renamed to "Wi-Fi RF Characteristics" Added Section 11.2 Module Placement for PCB Design Optimized Figure 12-1 Reflow Profile
2023-02-01	∨1.3	 Added module variants ESP32-C3-WROOM-02-N8 and ESP32-C3-WROOM-02U-N8 Updated the maximum value of "RF power control range" to 20 dBm in Table Bluetooth LE RF Characteristics

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Date	Version	Release notes
2022-11-08	v1.2	 Changed Table Ordering Information to Table ESP32-C3-WROOM-02 (ANT) Series Comparison¹ and Table ESP32-C3-WROOM-02U (CONN) Series Comparison Updated test condition descriptions and data in Section 6.4 Current Consumption Characteristics Updated "RF power control range" in Table Bluetooth LE RF Characteristics Added descriptions in Section 11.1 PCB Land Pattern
2022-06-13	V1.1	Updated Table Ordering Information
2021-08-20	v1.0	 Updated module description on the title page Deleted Section "About This Document" Restructured Section 1.1 Features Updated Table 7-3 TX EVM Test¹ Updated Table 7-6 RX Adjacent Channel Rejection Updated Chapter 8 Module Schematics Updated ESP32-C3-WROOM-O2U Module Dimensions Added descriptions in Section 10.2 Dimensions of External Antenna Connector Updated Section "Learning Resources" and renamed to Related Documentation and Resources Replaced "chip family" with "chip series" following Espressif's taxonomy
2021-05-17	v0.7	 Updated Section 4 Boot Configurations Updated ESP32-C3-WROOM-O2U Module Dimensions
2021-04-16	v0.6	Added information about ESP32-C3-WROOM-02U module
2021-03-05	v0.5	Preliminary release



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